NSN 5962-01-039-3456

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-039-3456

Body Length:

Between 0.750 inches and 0.795 inches

Body Width:

Between 0.245 inches and 0.300 inches

Body Height:

Between 0.120 inches and 0.195 inches

Maximum Power Dissipation Rating:

512.0 milliwatts

Operating Tempurature Range:

+0.0/+75.0 degrees celsius

Storage Tempurature Range:

-65.0/+160.0 degrees celsius

End Application:

Data display group type ol-17 (v) /uyk

Features Provided:

Hermetically sealed and monolithic and high speed and negative outputs and positive outputs and programmable and programmed and

schottky and w/enable and 3-state output

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Case Outline Source And Designator:

-0-001-ag joint electron device engineering council

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Memory Device Type:

Ram

Test Data Document:

46859-398-14171 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

NSN 5962-01-039-3456

Memory Microcircuit - Page 2 of 2

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